NSN 5961-01-365-0681

Semiconductor Device Set - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-365-0681 **Inclosure Material:** Ceramic **Overall Length:** 0.090 inches **Terminal Length:** 0.200 inches **Overall Height:** 0.030 inches **Internal Configuration:** Junction contact **Internal Junction Configuration:** Pnpn **Component Function Relationship:** Matched **Component Name And Quantity:** 7 semiconductor device diode **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 reverse breakdown voltage, dc **Current Rating Per Characteristic:** 10.00 microamperes collector current, dc peak **Power Rating Per Characteristic:** 100.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

A110a0